

PTO 09/993890

438	Subclass	ISSUE CLASSIFICATION
	Class	

PATENT NUMBER

U.S. UTILITY Patent Application

SCANNED *9* O.I.P.E. *10* PATENT DATE *11/18*

APPLICATION NO. 09/993890	CONT/PRIOR F	CLASS 438	SUBCLASS 25	ART UNIT 2812	EXAMINER <i>Johnson</i>
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APPLICANTS  
Satoru Yamagata  
Masanori Yoshimi

TITLE  
Method for manufacturing nonvolatile semiconductor memory with narrow variation in threshold voltages of memory cells

PTO-2040  
1299

ISSUING CLASSIFICATION							
ORIGINAL				CROSS REFERENCE(S)			
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
438							
INTERNATIONAL CLASSIFICATION							

Continued on Issue Slip Inside File Jacket

<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>	<b>DRAWINGS</b> Sheets Drwg. <i>10</i> Figs. Drwg. <i>27</i> Print Fig. <i>5B, 5C, 5D</i>			<b>CLAIMS ALLOWED</b> Total Claims    Print Claim for O.G.	
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____	_____ (Assistant Examiner)    _____ (Date)			<b>ISSUE FEE</b> Amount Due    Date Paid	
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